

## PWROK GENERATOR AND STARTUP LATCHING CIRCUIT

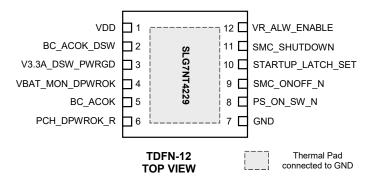
#### **General Description**

Renesas SLG7NT4229 is a low power and small form device. The SoC is housed in a 2.5mm x 2.5mm TDFN package which is optimal for using with small devices.

#### **Features**

- Low Power Consumption
- 3.3V Supply Voltage
- RoHS Compliant / Halogen-Free
- Pb-Free TDFN-12 Package
- MSL Level 1

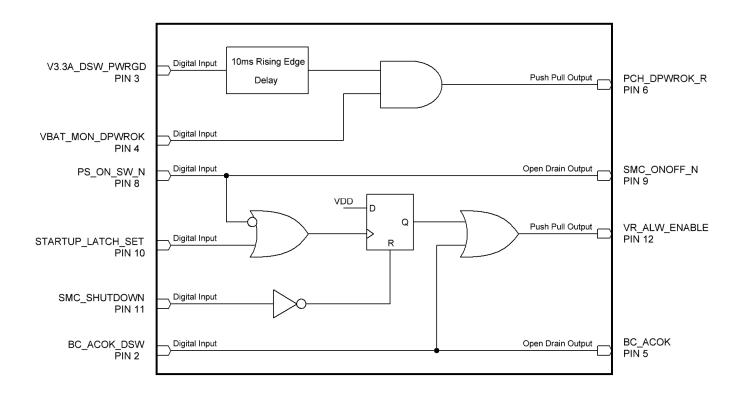
### **Pin Configuration**



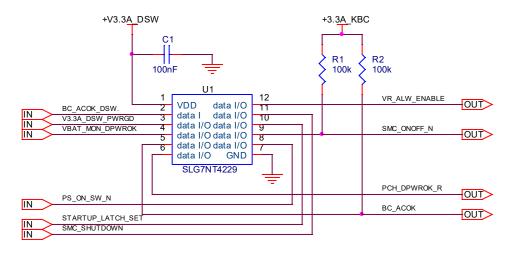
### **Output Summary**

- 2 Outputs Push Pull
- 2 Outputs Open Drain

## **Block Diagram**



# **Typical Application Circuit**





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# Pin Configuration

Pin #	Pin Name	Type	Pin Description
1	VDD	PWR	Supply Voltage
2	BC_ACOK_DSW	Input	Digital Input
3	V3.3A_DSW_PWRGD	Input	Digital Input
4	VBAT_MON_DPWROK	Input	Digital Input
5	BC_ACOK	Output	Open Drain
6	PCH_DPWROK_R	Output	Push Pull
7	GND	GND	Ground
8	PS_ON_SW_N	Input	Digital Input
9	SMC_ONOFF_N	Output	Open Drain
10	STARTUP_LATCH_SET	Input	Digital Input
11	SMC_SHUTDOWN	Input	Digital Input
12	VR_ALW_ENABLE	Output	Push Pull
Exposed	Exposed Bottom Pad	GND	Ground
Bottom Pad			

**Ordering Information** 

Part Number	Package Type
SLG7NT4229V	V = TDFN-12
SLG7NT4229VTR	VTR = TDFN-12 - Tape and Reel (3k units)



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## **Absolute Maximum Conditions**

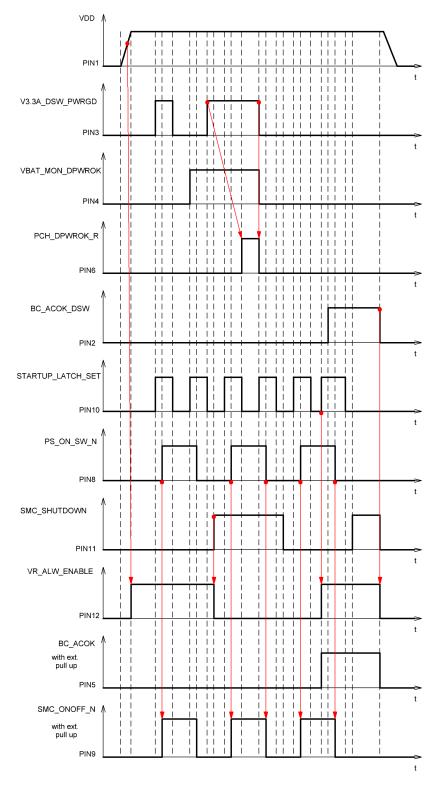
Parameter	Min.	Max.	Unit
V <sub>HIGH</sub> to GND	-0.3	7	V
Voltage at input pins	-0.3	7	V
Current at input pin	-1.0	1.0	mA
Storage temperature range	-65	150	°C
Junction temperature		150	°C

### **Electrical Characteristics**

(@ 25°C, unless otherwise stated)

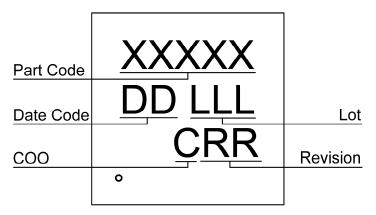
Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
$V_{DD}$	Supply Voltage		3.0	3.3	3.6	V
IQ	Quiescent Current	Static inputs and outputs		1		μΑ
TA	Operating Temperature		-40	25	85	°C
lι	Input Leakage Current	Leakage Current for Analog/Digital Inputs or outputs in High impedance state	-100		100	nA
Vон	Output Voltage High	Push Pull Logic Level Output, Iон=3mA	2.1			V
Vol	Output Voltage Low	Push Pull Logic Level Output, IoL=3mA			0.81	V
Vol	Output Voltage Low	Open Drain Logic Level Output, I <sub>OL</sub> =10mA			0.605	V
Vo	Maximal Voltage Applied to any PIN in High-Impedance State				VDD	>
VIH	HIGH-Level Input Voltage	Logic Input	1.8			V
VIL	LOW-Level Input Voltage	Logic Input			1.1	٧
loL	LOW-Level Output Current	Push Pull Current at, V <sub>OL</sub> =0.4V		1		mA
loL	LOW-Level Output Current	Open Drain Current at V <sub>OL</sub> =0.4V		7		mA
T <sub>DLY1</sub>	Delay1 Time		10		14	ms
Tsu	Start up Time	After VDD reaches 1.6V		7		ms

# Timing Diagrams





## **Package Top Marking**



XXXXX - Part Code Field: identifies the specific device configuration

DD - Date Code Field: Coded date of manufacture

LLL - Lot Code: Designates Lot #

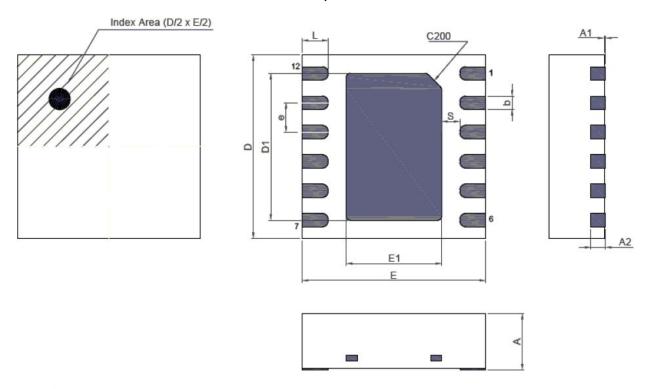
C – Assembly Site/COO: Specifies Assembly Site/Country of Origin

RR - Revision Code: Device Revision

Datasheet Revision	Programming Code Number	Part Code	Revision	Date
1.01	01	4229V	AA	02/25/2022

# **Package Drawing and Dimensions**

### 12 Lead TDFN Package JEDEC MO-229, Variation WDDE



#### Unit: mm

Symbol	Min	Nom.	Max	Symbol	Min	Nom.	Max
Α	0.70	0.75	0.80	D1	1.95	2.00	2.05
A1	0.005	-	0.060	E1	1.25	1.30	1.35
A2	0.15	0.20	0.25	е	0.40 BSC		
b	0.13	0.18	0.23	L	0.30	0.35	0.40
D	2.45	2.50	2.55	S	0.18	-	-
E	2.45	2.50	2.55				

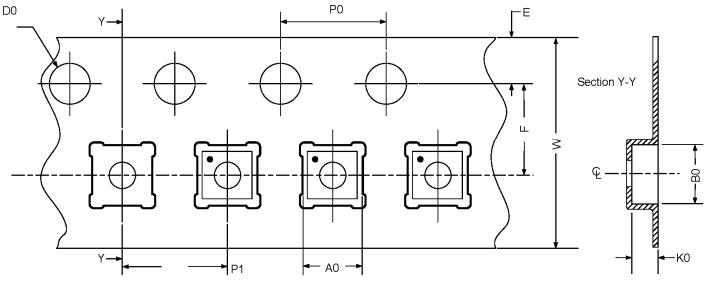
## **Tape and Reel Specification**

#0		Nominal	Max Units		Reel &	Trailer A		Leader B		Pocket (mm)	
Package Type	Pins	Package Size (mm)	per reel	per box	Hub Size (mm)	Pockets	Length (mm)	Pockets	Length (mm)	Width	Pitch
TDFN 12L 2.5x2.5mm 0.4P Green	12	2.5x2.5x0.75	3000	3000	178/60	42	168	42	168	8	4

## **Carrier Tape Drawing and Dimensions**

Package Type	Pocket BTM Length (mm)	Pocket BTM Width (mm)	Pocket Depth (mm)	Index Hole Pitch (mm)	Pocket Pitch (mm)	Index Hole Diameter (mm)	Index Hole to Tape Edge (mm)	Index Hole to Pocket Center (mm)	Tape Width (mm)
	Α0	В0	K0	P0	P1	D0	E	F	w
TDFN 12L 2.5x2.5mm 0.4P Green	2.75	2.75	1.05	4	4	1.55	1.75	3.5	8

Refer to EIA-481 Specifications



## **Recommended Reflow Soldering Profile**

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 4.6875 mm<sup>3</sup> (nominal). More information can be found at www.jedec.org.

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